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Trans-1,2-Difluorostilbenes: Promising Materials for High Dielectric Biaxiality Ferroelectric Mixtures

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A range of two- and three-ring liquid crystals have been synthesised that incorporate a trans-1,2-difluoroethene linking group. Some of the materials have surprisingly low melting points and high smectic C phase stability, and they exhibit the ideal phase sequence for ferroelectric hosts of smectic C to smectic A to nematic. The synthesis was accomplished in a convergent manner through the use of low-temperature lithiations to generate organometallics based on boron and tin. Palladium-catalysed cross-couplings and Michael-type reactions were used to generate the final mesogenic materials. The polar fluoro substituents enable the generation of ferroelectric mixtures with a high dielectric biaxiality which is very important in τV minimum driving schemes. The alkenic linking group in stilbenes normally confers instability, but the difluoro-substituted analogues are stable compounds.

Keywords: liquid crystals; synthesis; smectic C; ferroelectric

INTRODUCTION

Ferroelectricity in tilted smectic liquid crystals was first discovered by Meyer[1] over 25 years ago. The subsequent invention of the surface-stabilised ferroelectric display device by Clark and Lagerwall in 1980[2] demonstrated many advantages over existing nematic technology, such as extremely short switching times, high capacity for multiplex addressing, wide viewing angle, potential for extremely short

switching times, and high multiplexability due to the inherent bistability. All ferroelectric displays have very exacting material requirements, which include good mesomorphic behaviour (a low melting point and a wide smectic C temperature range, and smectic A and nematic phases above for good alignment), chemical and photochemical stability and a low viscosity (for short switching times). There are many other material requirements that need to be tailored for the particular ferroelectric device format, such as spontaneous polarisation (usually quite high for short switching times), tilt angle (usually 22.5° or 45°), birefringence (relatively high for conventional back-lit devices and very low for reflective mode, LCOS devices), and a high dielectric biaxiality (for devices that operate using the τV minimum driving scheme).[3-6]

In terms of materials, it is well recognised that the best way of achieving ferroelectricity in liquid crystals is to use a base mixture of achiral compounds (e.g., 1-4)[7-10] which enables the fine-tuning of mesomorphic behaviour and many important physical properties, such as dielectric and optical properties, and particularly the requirement for a low viscosity. Such achiral host mixtures are then doped with a small quantity of a chiral material (e.g., 5 and 6), which need not be

mesogenic, to provide the necessary chirality, which on removal of the macroscopic helical structure generates the ferroelectric properties.

Ferroelectric mixtures based on the *ortho*-difluoroterphenyls (e.g., 4 and 5 have a high dielectric biaxiality and hence make excellent host materials for τV minimum devices.[3,5,7] Dielectric biaxiality ($\delta \epsilon$) is proportional to the perpendicular dielectric permittivity (ϵ_{\perp}), and hence a high lateral dipole confers a high $\delta \epsilon$.

$$R(O) \longrightarrow F \xrightarrow{F} (F) \xrightarrow{(F)} (O)R^{i} \qquad R(O) \longrightarrow F \xrightarrow{F} (F) \xrightarrow{(F)} (O)R^{i}$$

The aim of this work was to design and synthesise materials (types I and II) that combine attributes of high dielectric biaxiality, low viscosity and low melting point with moderately high smectic C phase stability. Two-ring structures would minimise viscosity and melting point, and the difluoroethene linking group was used in order to assess the extent to which the polar fluoro substituents would promote the generation of the tilted smectic C phase, and ultimately evaluate their influence on dielectric biaxiality. Additionally, the *ortho*-difluorophenyl unit has been incorporated into the structures to enhance dielectric biaxiality. Two three-ring analogues have been synthesised to generate very high smectic C phase stability and to broaden the range of materials available for mixtures.

SYNTHESIS

As the required physical properties of liquid crystals become increasingly exacting for the applications of the future, then the required molecular structures are more complex and hence the synthesis is more demanding. A precise combination of structural moieties is required to generate desired physical properties such as

ideal mesomorphic behaviour, low viscosity, and tailored optical and dielectric properties, and tilt angle and spontaneous polarisation.

Chlorotrifluoroethene (7) was treated with sec-BuLi at low temperature to generate the alkenyllithium derivative which was quenched with trimethyl borate to provide trifluoroethenylboronic acid (8) as a colourless powder in excellent yield (Scheme 1). Boronic acid 8 was then subjected to a palladium-catalysed cross-coupling reaction with aryl bromide 10 under standard conditions, unfortunately no reaction occurred. The lack of reaction was not really surprising

considering the known susceptibility of electron-deficient arylboronic acids to undergo hydrodeboronation. The problem was circumvented by preparing the tributyltin derivative (9) from chlorotrifluoroethene (7) in a similar manner to that used in the preparation of the boronic acid (8). A Stille coupling of the tributyl(trifluoroethenyl)stannane (9) provided a good yield of the trifluorostyrene analogue 11. A Michaeltype addition of the aryllithium, prepared from an aryl bromide, to the trifluorostyrene 11 and subsequent elimination of lithium fluoride provided the desired 1,2-difluoroalkenes 16-19. However, the initial attempt to generate the lithium salt of aryl bromide 12 was carried out in diethyl ether; no aryllithium was generated and a butyl chain, from the butyllithium, was introduced to give compound 15. Subsequent attempts to generate the lithium salt of aryl bromides were effected successfully in THF, and 1,2-difluoroalkenes 16-19 were generated as expected. Isolation of the desired trans isomers of 1,2-difluoroalkenes proved simple by column chromatography.

Scheme 2 shows a similar approach to that outlined in Scheme 1, but the trifluorovinyltin compound (9) was coupled to an alkyl-substituted aryl bromide (12) to generate an alkyl-substituted trifluorostyrene 20 which facilitated the generation of an alkoxy-alkyl-1,2-difluoroalkene (23) in 22% yield and a dialkyl example (24) in 25% yield. The ortho-difluorophenyl class of compound has been most successful in

the generation of the smectic C phase. The lateral dipole generated from the two aryl fluoro substituents is sufficiently powerful to promote molecular tilting, yet the steric effect is minimal thereby upholding liquid crystallinity.

Compound 25 (Scheme 3) has been employed in previous work to generate ferroelectric host materials and was used here in a Stille coupling with the trifluorovinyltin 9 to provide the desired *ortho*-difluoro(trifluorovinyl)phenyl system 26 in excellent yield. Three aryl bromides (12, 10 and 27) were then employed in lithiation procedures and Michael-type addition to the styrene 26 to generate three final difluorostilbene mesogens with an *ortho*-difluorophenyl unit (28-30).

In order to extend the core system for much higher phase stability of the smectic C phase a difluorostilbene with a bromo substituent was targeted to enable subsequent Suzuki couplings to facilitate the introduction of another aryl ring (Scheme 4). The selective lithiation of 1-bromo-4-iodobenzene (31) and a subsequent Michael-type addition to the trifluorostyrene 20 generated the bromo-substituted difluorostilbene 32. Aryl bromide 32 was then employed in separate Suzuki coupling reactions with arylboronic acid 33 and

ortho-difluorophenylboronic acid 34 to generate two analogous phenyl-substituted 1,2-difluorostilbenes (35 and 36) in good yield.

4a ... (i) Compound 31, n-BuLi, THF; (ii) compound 20, THF; (iii) 10% HCl. 4b ... Pd(PPh₃)₄, 2M Na₂CO₃, DME, H₂O.

MESOMORPHIC PROPERTIES

Stilbene mesogens with terminal alkyl or alkoxy chains exhibit ordered smectic phases, particularly tilted analogues, but they are photochemically unstable. [11,12] Some difluorostilbenes have also been reported, and these materials are photochemically stable, however, their mesophase morphology was not characterised. [13]

$$C_{7}H_{15}$$
 $C_{7}H_{15}$
 $C_{7}H_{19}$
 $C_{88.5}$
 $C_{7}H_{19}$
 $C_{88.5}$

The parent difluorostilbenes reported here (16, 17, 23 and 24) have low melting points, generally show the smectic C, smectic A and nematic phases, and have remarkably high smectic C phase stability

compared with two-ring esters[14] and phenylpyrimidines.[9] As expected, the dialkoxy analogue (17) has a high melting point, and the smectic C phase stability is so high as to preclude the generation of a smectic A phase. The dialkyl compound (24) has a very low melting point, but the smectic C phase is monotropic. The alkoxy-alkyl analogues (16 and 23) show the best compromise of low melting point with remarkably high smectic C phase stability.

Lateral fluoro substituents in the phenyl rings usually reduce melting point and liquid crystal phase stability. Compared with their parent analogues, compounds 18, 19, 28 and 29 all have lower melting points. The outer-edge fluoro substituent of compound 18 might have been expected to promote the exhibition of a smectic A phase, but the smectic C phase stability has been maintained, thus showing the strong tendency towards molecular tilting. The inner-core fluoro substituent of compound 19 has caused the elimination of all smectic phases to give a nematogen over a wide temperature range, this result is a typical effect of such fluoro-substitution.[15] The most interesting result is that the smectic C phase stability of the dialkoxy system (29) is actually lower than for the alkoxy-alkyl analogue (28); this contrasts markedly with the case seen above (compounds 16 and 17) and other

typical examples,[16] yet the nematic phase stability behaves normally. Terminal trifluoromethyl compounds typically support the smectic A phase, and compound 30 is no exception and would serve to ensure the presence of a smectic A phase in mixtures. Although compound 32 was prepared as an intermediate it exhibits a smectic A phase.

Although compounds 35 and 36 have three rings, they exhibit extremely high smectic C phase stability considering their fluorohydrocarbon construction. In addition to a smectic A phase above the smectic C phase, the parent system (35) exhibits underlying, ordered smectic I and Smectic F phases. As is typical, the *ortho*-difluorophenyl unit in compound 36 ensures a low melting point and eliminates the ordered smectic phases, and the smectic phase stability is now reduced to below the limit of molecular tilting to leave the smectic C phase as the sole smectic phase over a very wide temperature range.

CONCLUSIONS

The difluoroethene linking group is most effective in generating the tilted smectic C phase from materials of two-ring construction with relatively short terminal chains. The three-ring analogues exhibit remarkably high smectic C phase stability considering their fluorohydrocarbon construction. Low melting points are found, particularly for the lateral fluoro-substituted examples, where even with three rings the melting point is very low. The difluoroalkene linkage has proved to be photochemically stable which supports previous reports.[13] Thus the materials show great promise as host materials for

ferroelectric mixtures, and their physical properties will be reported later by our collaborators at DERA (Malvern).

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